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Designer's Data Sheet

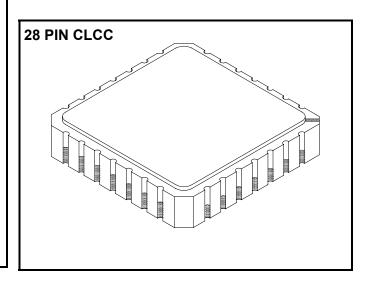
FEATURES:

- Extremely Low Forward Voltage Drop
- Low Reverse Leakage
- Hermetically Sealed Surface Mount Package
- Guard Ring for Overvoltage Protection
- Ceramic Seals for Improved Hermeticity
- Custom Lead Forming Available
- Eutectic Die Attach
- 175°C Operating Junction Temperature

Also Available in the following configurations:

- Common Cathode Centertap: SSR1010-28CT
- Common Anode Centertap: SSR1010-28CA
- Doubler: SSR0510-28D
- TX, TXV, and Space Level Screening Available

10 AMPS 80-100 VOLTS **SCHOTTKY** RECTIFIER



MAXIMUM RATINGS		Symbol	Value	Units
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SSR1008-28 SSR1009-28 SSR1010-28	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	80 90 100	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A =25 °C)		I_0	10	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on I _O , allow junction to reach equilibrium between pulses, T _A =25 °C)		I_{FSM}	200	Amps
Operating and Storage Temperature		T _{OP} & Tstg	-65 to +175	°C
Maximum Thermal Resistance Junction to Case		$R_{ heta JC}$	6.0	°C/W



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ELECTRICAL CHARACTERISTICS		Symbol	Max	Unit
Instantaneous Forward Voltage Drop (T _A = 25 °C, Pulse)	$I_F = 1 \text{ Amps}$ $I_F = 5 \text{ Amps}$ $I_F = 10 \text{ Amps}$	$egin{array}{c} V_{F1} \ V_{F2} \ V_{F3} \end{array}$	0.56 0.72 0.82	Volts
Instantaneous Forward Voltage Drop (I _F = 10 Amps, T _A = -55 °C, Pulse)		$ m V_{F4}$	0.87	Volts
Reverse Leakage Current (Rated V _R , T _A = 25°C, Pulse)		I_{R1}	100	μА
Reverse Leakage Current (Rated V _R , T _A = 100 °C, Pulse)		I_{R2}	5	mA
Junction Capacitance (V _R =10 V _{DC} , T _A = 25°C, f = 1 MHz)		C _J	400	pF

